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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/812,880	03/31/2004	Kyoko Egashira	60188-827	4575
7590 08/02/2006			EXAMINER	
Jack Q. Lever, Jr. McDERMOTT, WILL & EMERY 600 Thirteenth Street, N.W. Washington, DC 20005-3096			NHU, DAVID	
			ART UNIT	PAPER NUMBER
			2818	
			DATE MAILED: 08/02/2006	

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)			
	10/812,880	EGASHIRA ET AL.			
Office Action Summary	Examiner	Art Unit			
	David Nhu	2818			
The MAILING DATE of this communication app Period for Reply	ears on the cover sheet with the c	orrespondence address			
A SHORTENED STATUTORY PERIOD FOR REPLY WHICHEVER IS LONGER, FROM THE MAILING DA - Extensions of time may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication. - If NO period for reply is specified above, the maximum statutory period w - Failure to reply within the set or extended period for reply will, by statute, Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	ATE OF THIS COMMUNICATION 36(a). In no event, however, may a reply be tin will apply and will expire SIX (6) MONTHS from a cause the application to become ABANDONE	N. nely filed the mailing date of this communication. D (35 U.S.C. § 133).			
Status					
1) Responsive to communication(s) filed on 2a) This action is FINAL . 2b) This 3) Since this application is in condition for allowar closed in accordance with the practice under E	action is non-final. nce except for formal matters, pro				
Disposition of Claims	•				
4) ☐ Claim(s) 1-19 is/are pending in the application. 4a) Of the above claim(s) 1-11 is/are withdrawn 5) ☐ Claim(s) is/are allowed. 6) ☐ Claim(s) 12-19 is/are rejected. 7) ☐ Claim(s) is/are objected to. 8) ☐ Claim(s) are subject to restriction and/or Application Papers 9) ☐ The specification is objected to by the Examine	r election requirement.				
10) The drawing(s) filed on is/are: a) access applicant may not request that any objection to the example Replacement drawing sheet(s) including the correction of the original transfer and the correction is objected to by the Example 11).	epted or b) objected to by the Idrawing(s) be held in abeyance. See ion is required if the drawing(s) is obj	e 37 CFR 1.85(a). sected to. See 37 CFR 1.121(d).			
Priority under 35 U.S.C. § 119					
 12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a) All b) Some * c) None of: 1. Certified copies of the priority documents have been received. 2. Certified copies of the priority documents have been received in Application No 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received. 					
Attachment(s) 1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948)	4) Interview Summary Paper No(s)/Mail Da	(PTO-413)			
2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date		atent Application (PTO-152)			

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FINAL

DETAILED ACTIONS

Claims Objection

1. Claims 17, 19, The first conductive film is made of a metal film; the second conductive film is made of an aluminum alloy" are not described/supported in the specifications.

Claim Rejections - 35 USC § 102

2. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (e) the invention was described in a patent granted on an application for patent by another filed in the United States before the invention thereof by the applicant for patent, or on an international application by another who has fulfilled the requirements of paragraphs (1), (2), and (4) of section 371(c) of this title before the invention thereof by the applicant for patent.
- 3. Claims 12-19 are rejected under 35 U.S.C. 102 (b) as being anticipated by Lachner (6,893,935 B2), and Jung (6,555,428 B2).

Regarding claims 12, Lachner, (see figures 4a-4c, 5a-5c, col. 4, lines 7-67, col. 5, lines 1-15), teaches a semiconductor device comprising: an insulating layer 10; an interconnect 14 made of a first conductive film and a second conductive film that are stacked in sequence from the interconnect underside on the insulating film (see figures 4c, 5c); on the insulating film, a capacitor 1 composed of: a lower capacitor electrode 2 made of the first conductive film; a dielectric film 3 formed on the lower capacitor electrode; and an upper capacitor electrode 11 mad of the second conductive film, wherein each of the lower capacitor electrode, the dielectric film, and the upper capacitor electrode has a same pattern (see figures 5a-5c); and lower contacts 17, 18 are formed in the insulating film 10 on a bottom surface of the lower

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capacitor electrode, the lower contacts being connected to the lower capacitor electrode (see figure 5c).

Regarding claim 13, Lachner, (see figures 5d, 5e), teaches a lower insulating film 10 is formed beneath the insulating; a lower interconnect is formed on the lower insulating film; and the lower contacts are connected to the lower interconnect.

Regarding claim 14, Lachner, (see figure 5c), teaches a surface of the insulating film on which the capacitor is formed is planarized.

Regarding claim 15, Lachner, (see figures 5d-5f), teaches an upper insulating film 5 is formed so as to cover the capacitor and the inte5rconnect; and upper contacts 83, 85 are formed in the upper insulating film on the upper surface of the upper capacitor electrode, the upper contacts being connected to the upper capacitor electrode.

Regarding claim 16, Lachner, (see figures 5d-5f), teaches an upper interconnect is formed on the upper insulating film; and the upper contacts are connected with the upper interconnect.

Regarding claims 17-19, Lachner, (see col. 4, lines 32-47, col. 5, lines 10-16), also teahes the conductive films are made of metal nitride (TiN), Aluminum; the dielectric film is SiN.

Conclusion

- 5. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure: Ono'239, Adan'131, Kirlin'213 are cited as of interest.
- 6. A shortened statutory period for response to this action is set to expired 3 (three) months and 0 (zero) day from the date of this letter. Failure to respond within the period for response will cause the application to become abandoned(see 710.02 (b)).

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should be directed to David Nhu (571)272-1792. The examiner can normally be reached

7. Any inquiry concerning this communication on earlier communications from the examiner

on Monday-Friday from 7:30 AM to 5:00 PM. The examiner's supervisor, David Nelms can

be reached on (571)272-1787.

The fax phone number for the organization where this application or proceeding is assigned

is (571)273-8300.

Information regarding the status of an application may be obtained from the patent application

information retrieval (PAIR) system. Status information for published applications may be

obtained from either Private PAIR or Public PAIR. Status information for unpublished

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PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

David Nhu

July 29, 2006